## **Amendments to the Abstract:**

Please replace the abstract with the following replacement Abstract:

Methods and systems for improving repairing efficiency in non-volatile memory. Repairing data may be read from an information array associated with the non-volatile memory. The repairing data is generally read to a volatile latch associated with the non-volatile memory. An error correction coding circuit (ECC) circuit can be enabled during reading of the repairing data to thereby identify and repair for identifying and repairing defective columns or rows associated with the non-volatile memory, despite errors in the repairing data read outregardless of the corruption of the columns.